Vishay Siliconix

Automotive N-Channel 80 V (D-S) 175 °C MOSFET

PowerPAK® 1212-8W Single **Bottom View**

Marking code: Q058

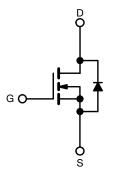
PRODUCT SUMMARY				
V _{DS} (V)	80			
$R_{DS(on)}(\Omega)$ at $V_{GS} = 10 \text{ V}$	0.0460			
$R_{DS(on)}(\Omega)$ at $V_{GS} = 4.5 \text{ V}$	0.0700			
I _D (A)	12			
Configuration	Single			

FEATURES

- TrenchFET® power MOSFET
- AEC-Q101 qualified
- 100 % Rq and UIS tested
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912







N-Channel MOSFET

ORDERING INFORMATION	
Package	PowerPAK 1212-8W
Lead (Pb)-free and halogen-free	SQSA82CENW

ABSOLUTE MAXIMUM RATING					
PARAMETER		SYMBOL	LIMIT	UNIT	
Drain-source voltage		V_{DS}	80	V	
Gate-source voltage	V_{GS}	± 20	V		
Continuous drain current	T _C = 25 °C ^a	1	12	А	
	T _C = 125 °C	l _D	9.68		
Continuous source current (diode conductio	n) ^a	I _S	12		
Pulsed drain current ^b		I _{DM}	35	1	
Single pulse avalanche current	J 0.1 ml J	I _{AS}	13		
Single pulse avalanche energy	L = 0.1 mH	E _{AS}	8.45	mJ	
Maximum power dissipation	T _C = 25 °C		27	14/	
	T _C = 125 °C	P_{D}	9	W	
Operating junction and storage temperature range		T _J , T _{stg}	-55 to +175		
Soldering recommendations (peak temperature) d, e		<u> </u>	260	°C	

THERMAL RESISTANCE RATINGS				
PARAMETER		SYMBOL	LIMIT	UNIT
Junction-to-ambient	PCB mount c	R_{thJA}	81	°C/W
Junction-to-case (drain)		R_{thJC}	5.5	C/VV

Notes

- a. Package limited
- b. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 % c. When mounted on 1" square PCB (FR4 material)
- See solder profile (www.vishay.com/doc?73257). The PowerPAK1212-8W package may have visible exposed Cu at the end of the lead terminals due to the singulation process. However, the leads also have plated indents on the top and bottom surfaces that promote the formation of a solder filet compatible with automated optical inspection methods
- e. Rework conditions: manual soldering with a soldering iron is not recommended



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SPECIFICATIONS (T _C = 25 °C, unparameter	SYMBOL		T CONDITIONS	MIN.	TYP.	MAX.	UNIT	
Static	STRIBOL	ILO	TOUNDITIONS	IVIIIV.	1115.	WIAA.	ONIT	
Drain-source breakdown voltage	V _{DS}	Vgs	= 0, I _D = 250 μA	80	_	_		
Gate-source threshold voltage	V _{GS(th)}	40	V _{GS} , I _D = 250 μA	1.5	2.0	2.5	V	
Gate-source leakage	I _{GSS}		0 V, V _{GS} = ± 20 V	-	-	± 100	nA	
· ·		V _{GS} = 0 V	V _{DS} = 80 V	-	_	1		
Zero gate voltage drain current	I _{DSS}	V _{GS} = 0 V	V _{DS} = 80 V, T _J = 125 °C	-	-	50	μΑ	
		V _{GS} = 0 V	V _{DS} = 80 V, T _J = 175 °C	-	-	150		
On-state drain current ^a	I _{D(on)}	V _{GS} = 10 V	V _{DS} ≥ 5 V	10	_	-	Α	
	(- /	V _{GS} = 10 V	I _D = 3.5 A	-	0.0370	0.0460		
	_	V _{GS} = 10 V	I _D = 3.5 A, T _J = 125 °C	-	-	0.0798		
Drain-source on-state resistance a	$R_{DS(on)}$	V _{GS} = 10 V	I _D = 3.5 A, T _J = 175 °C	-	-	0.0971	Ω	
		V _{GS} = 4.5 V	I _D = 3 A	-	0.0495	0.0700		
Forward transconductance b	9 _{fs}	V _{DS} =	= 15 V, I _D = 3.5 A	-	14	-	S	
Dynamic ^b				ı		l		
Input capacitance	C _{iss}			-	413	580		
Output capacitance	C _{oss}	$V_{GS} = 0 V$	V _{DS} = 25 V, f = 1 MHz	-	207	290	рF	
Reverse transfer capacitance	C _{rss}			-	12	17		
Total gate charge ^c	Qg			-	6.40	9.60		
Gate-source charge ^c	Q _{gs}	V _{GS} = 10 V	$V_{DS} = 40 \text{ V}, I_D = 5 \text{ A}$	-	1.65	-	nC	
Gate-drain charge ^c	Q _{gd}			-	0.66	-		
Gate resistance	Rg		f = 1 MHz	0.49	0.98	1.47	Ω	
Turn-on delay time ^c	t _{d(on)}			-	7	12		
Rise time ^c	t _r	V _{DD} =	= 40 V, R _L = 10 Ω	-	3	6	1	
Turn-off delay time ^c	t _{d(off)}	$I_D \cong 4 A, \$	$I_{\rm GEN}$ = 10 V, $R_{\rm g}$ = 1 Ω	-	14	23	ns	
Fall time ^c	t _f			-	3	6		
Source-Drain Diode Ratings and Charact	eristic ^b							
Pulsed current ^a	I _{SM}			-	-	35	Α	
Forward voltage	V _{SD}	l _F =	3.5 A, V _{GS} = 0 V	-	0.83	1.1	V	
Body diode reverse recovery time	t _{rr}			-	19	38	ns	
Body diode reverse recovery charge	Q _{rr}	l _F = 5 A, di/dt = 100 A/μs		-	13	26	nC	
Reverse recovery fall time	t _a			-	11	-	J -	
Reverse recovery rise time	t _b			-	8	-	ns	
Body diode peak reverse recovery current	I _{RM(REC)}			-	-1.16	-	Α	

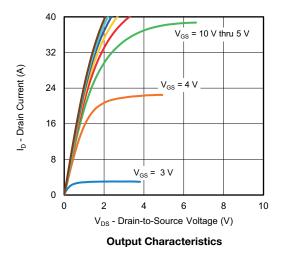
Notes

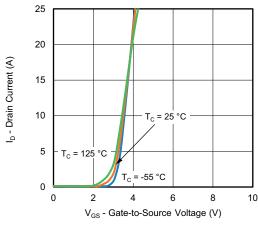
- a. Pulse test; pulse width $\leq 300~\mu s,$ duty cycle $\leq 2~\%$
- b. Guaranteed by design, not subject to production testing
- c. Independent of operating temperature

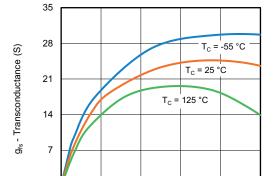
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)





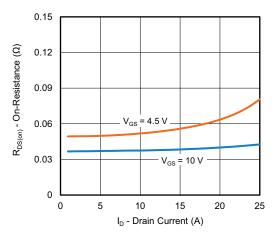


10

0

5

Transfer Characteristics

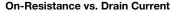


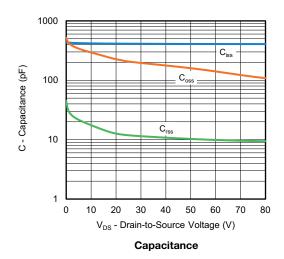
I_D - Drain Current (A) **Transconductance**

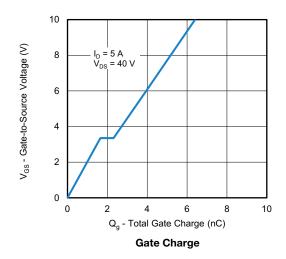
15

20

25

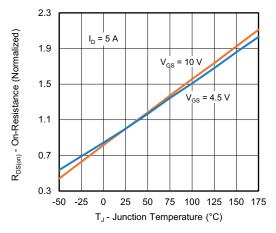




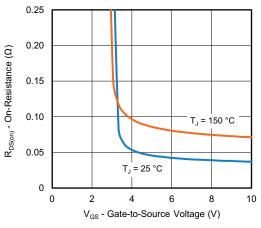




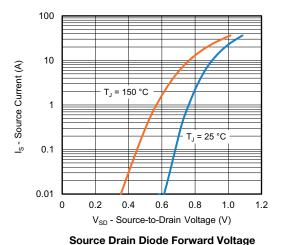
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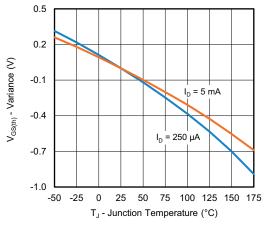


On-Resistance vs. Junction Temperature

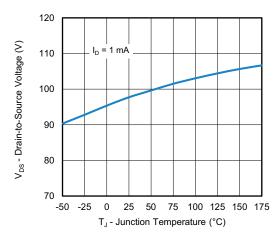


On-Resistance vs. Gate-to-Source Voltage

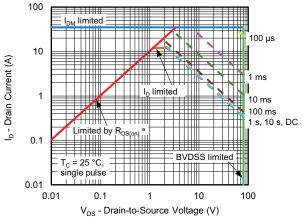




Threshold Voltage



Drain Source Breakdown vs. Junction Temperature



Safe Operating Area

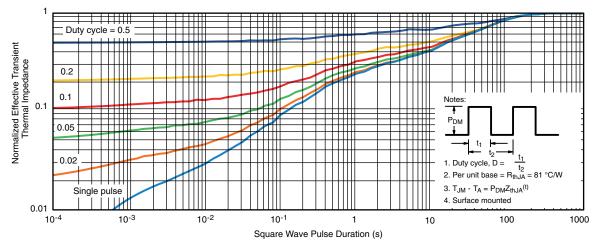
Note

a. V_{GS} > minimum V_{GS} at which $R_{DS(on)}$ is specified

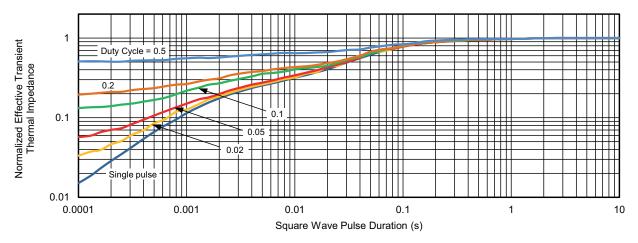
For technical questions, contact: automostech



THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Ambient



Normalized Thermal Transient Impedance, Junction-to-Case

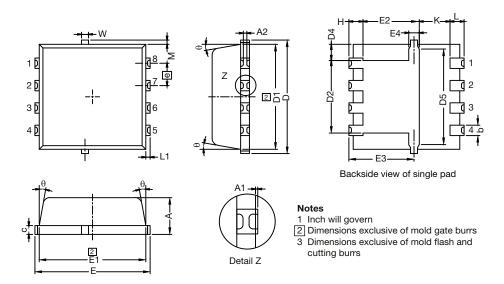
Note

- The characteristics shown in the two graphs
 - Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)
 - Normalized Transient Thermal Impedance Junction-to-Case (25 °C) are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package / tape drawings, part marking, and reliability data, see www.vishay.com/ppg?63157.



PowerPAK® 1212-8W Case Outline



DIM.		MILLIMETERS			INCHES			
DIN.	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.		
Α	0.97	1.04	1.12	0.038	0.041	0.044		
A1	0	-	0.05	0	-	0.002		
A2	0	-	0.13	0	-	0.005		
b	0.23	0.30	0.41	0.009	0.012	0.016		
С	0.23	0.28	0.33	0.009	0.011	0.013		
D	3.20	3.30	3.40	0.126	0.130	0.134		
D1	2.95	3.05	3.15	0.116	0.120	0.124		
D2	1.98	2.11	2.24	0.078	0.083	0.088		
D4	0.47 typ.			0.0185 typ.				
D5		2.3 typ.		0.090 typ.				
E	3.20	3.30	3.40	0.126	0.130	0.134		
E1	2.95	3.05	3.15	0.116	0.120	0.124		
E2	1.47	1.60	1.73	0.058	0.063	0.068		
E3	1.75	1.85	1.98	0.069	0.073	0.078		
E4		0.34 typ.		0.013 typ.				
е		0.65 BSC.		0.026 BSC				
K		0.86 typ.		0.034 typ.				
Н	0.30	0.41	0.51	0.012	0.016	0.020		
L	0.30	0.43	0.56	0.012	0.017	0.022		
L1	0.06	0.13	0.20	0.002	0.005	0.008		
θ	0°	-	12°	0°	-	12°		
W	0.15	0.25	0.36	0.006	0.010	0.014		
М	0.125 typ.				0.005 typ.			

DWC: 6020

DWG: 6032



RECOMMENDED MINIMUM PADS FOR PowerPAK® 1212-8 Single



Recommended Minimum Pads Dimensions in Inches/(mm)

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APPLICATION NOTE



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